



NPN SILICON PLANAR EPITAXIAL TRANSISTOR

2N6705



TO-237 Plastic Package

General Purpose Medium Power Amplifier

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

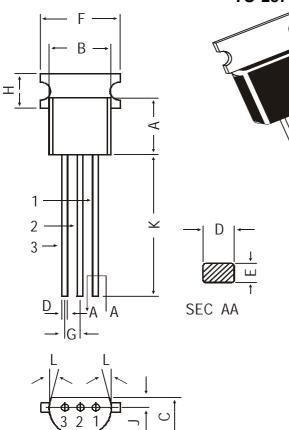
DESCRIPTION	SYMBOL	VALUE	UNIT	
Collector -Base Voltage	V _{CBO}	60	V	
Collector -Emitter Voltage	V _{CEO}	45	V	
Emitter Base Voltage	V _{EBO}	5	V	
Collector Current Continuous	I _C	1.5	А	
Total Power Dissipation	P _D	850	mW	
Operating and Storage Junction	Τ _i , Τ _{stg}	-55 to +150	°C	
Temperature Range	, ,			

ELECTRICAL CHARACTERISTICS (Ta=25°C Unless Specified Otherwise)

DESCRIPTION	SYMBOL TEST CONDITION		MIN	MAX	UNIT
Collector Emitter Voltage	V _{CEO}	I _C =10mA, I _B =0	45		V
Collector -Base Voltage	V _{CBO}	I _C =100μA, I _E =0	60		V
Emitter-Base Voltage	V _{EBO}	I _E =10μΑ, I _C =0	5		V
Collector Cut off Current	I _{CBO}	V _{CB} =60V, I _E =0		0.1	μΑ
Emitter Cut off Current	I _{EBO}	$V_{EB}=4V, I_{C}=0$		0.1	μΑ
DC Current Gain	h _{FE}	I _C =50mA,V _{CE} =2V	40		
		I _C =250mA,V _{CE} =2V	40	250	
		I _C =500mA,V _{CE} =2V	25		
Collector Emitter Saturation Voltage	V _{CE(sat)}	I _C =500mA,I _B =50mA		0.5	V
		I _C =1A,I _B =100mA		1	V
Transition Frequency	f⊤	V _{CE} =10V, I _C =200mA,	50	400	MHz

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DIM	MIN.	MAX.	
А	4.32	5.33	
В	4.45	5.20	
С	3.18	4.19	
D	0.41	0.55	
Е	0.35	0.50	
F		5.40	
G	1.14	1.40	
Н		2.54	
К	12.70		
L	5 DEG		
J	1.14	1.53	
	A B C D E F G H K	A 4.32 B 4.45 C 3.18 D 0.41 E 0.35 F G 1.14 H K 12.70 L 5 D	

PIN CONFIGURATION

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- 1. BASE
- 2. COLLECTOR
- 3. EMITTER

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-237 Bulk	1K/polybag	240 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	26.2 kgs
TO-237 T&A	2K/ammo box	725 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	13.8 kgs

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Disclaimer

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Data Sheet